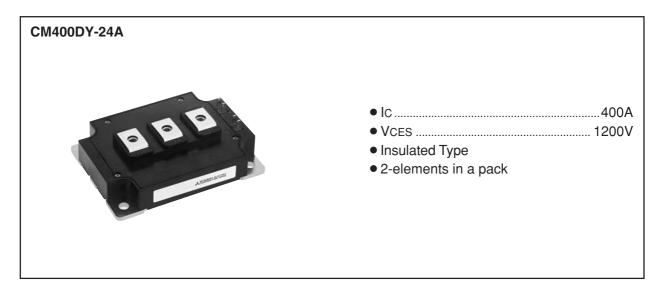
MITSUBISHI IGBT MODULES

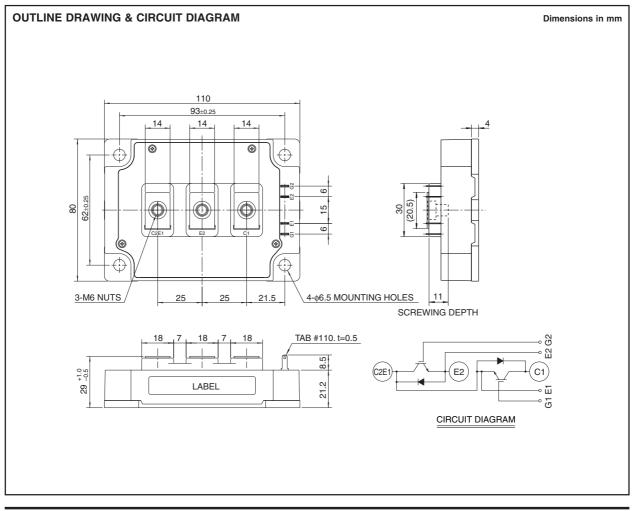


HIGH POWER SWITCHING USE



#### **APPLICATION**

AC drive inverters & Servo controls, etc





#### **HIGH POWER SWITCHING USE**

#### ABSOLUTE MAXIMUM RATINGS (Tj = 25°C, unless otherwise specified)

Symbol	Parameter	Conditions		Ratings	Unit	
VCES	Collector-emitter voltage	G-E Short		1200	V	
VGES	Gate-emitter voltage	C-E Short		±20	V	
Ic	Collector current	DC, Tc = $85^{\circ}C^{*1}$		400	^	
Ісм	Collector current	Pulse	(Note 2)	800	A	
IE (Note 1)	Emitter current			400	•	
IEM (Note 1)	Emiller current	Pulse	(Note 2)	800	A	
PC (Note 3)	Maximum collector dissipation	$TC = 25^{\circ}C^{*1}$		2710	W	
Tj	Junction temperature			-40 ~ +150	°C	
Tstg	Storage temperature			-40 ~ +125	°C	
Viso	Isolation voltage	Terminals to base plate, f = 60Hz, AC 1 min	ute	2500	Vrms	
_	Texes at search	Main terminals M6 screw		3.5 ~ 4.5	N • m	
	Torque strength	Mounting M6 screw		3.5 ~ 4.5		
_	Weight	Typical value		580	g	

#### ELECTRICAL CHARACTERISTICS (Tj = 25°C, unless otherwise specified)

Cumples	Devementer	Test conditions		Limits			
Symbol	Parameter			Min.	Тур.	Max.	Unit
ICES	Collector cutoff current	VCE = VCES, VGE = 0V		_	_	1	mA
VGE(th)	Gate-emitter threshold voltage	IC = 40mA, VCE = 10V		6	7	8	V
IGES	Gate leakage current	$\pm VGE = VGES, VCE = 0V$		_	_	0.5	μA
VCE(sat)	Collector-emitter saturation voltage	IC = 400A, VGE = 15V		—	2.1	3.0	V
		$T_j = T_j$	125°C	_	2.4		
Cies	Input capacitance			_		70	
Coes	Output capacitance			—		6	nF
Cres	Reverse transfer capacitance	VGE = 0V		_	_	1.4	
QG	Total gate charge	VCC = 600V, IC = 400A, VGE = 15V		_	2000	_	nC
td(on)	Turn-on delay time			_	_	550	
tr	Turn-on rise time	Vcc = 600V, Ic = 400A VGE = $\pm 15V$ RG = $0.78\Omega$ , Inductive load IE = 400A		_	_	180	ns
td(off)	Turn-off delay time			_	_	600	
tr	Turn-off fall time			_	_	350	
trr (Note 1)	Reverse recovery time			_	_	250	ns
Qrr (Note 1)	Reverse recovery charge			_	16	_	μC
VEC(Note 1)	Emitter-collector voltage	IE = 400A, VGE = 0V		_	_	3.8	V
Rth(j-c)Q	<b>T</b> I I I I	IGBT part (1/2 module) <sup>*1</sup>		_	_	0.046	K/W
Rth(j-c)R	Thermal resistance	FWDi part (1/2 module) <sup>*1</sup>		_	_	0.085	
Rth(c-f)	Contact thermal resistance	Case to heat sink, Thermal compound Applied (1/2 module)*2		_	0.02	_	
Rg	External gate resistance		, í	0.78	_	10	Ω

\*1 : Case temperature (Tc), heat sink temperature (Tt) measured point is just under the chips. \*2 : Typical value is measured by using thermally conductive grease of  $\lambda = 0.9[W/(m \cdot K)]$ .

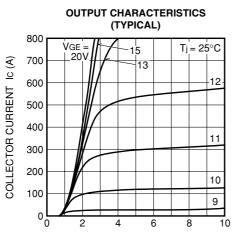
Note 1. IE, VEC, trr & Qrr represent characteristics of the anti-parallel, emitter-collector free-wheel diode (FWDi).

Pulse with and repetition rate should be such that the device junction temperature (Tj) does not exceed Tjmax rating.
Junction temperature (Tj) should not increase beyond 150°C.



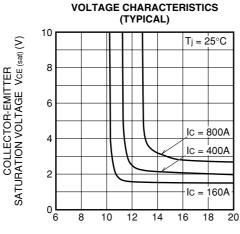
#### **HIGH POWER SWITCHING USE**



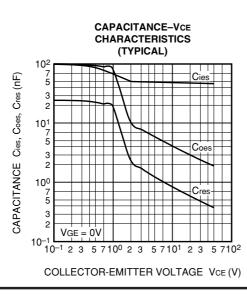


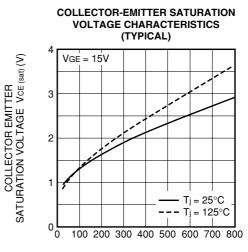
COLLECTOR-EMITTER VOLTAGE VCE (V)

**COLLECTOR-EMITTER SATURATION** 



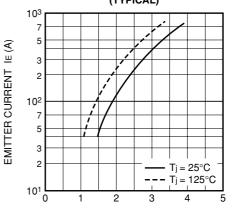
GATE-EMITTER VOLTAGE VGE (V)



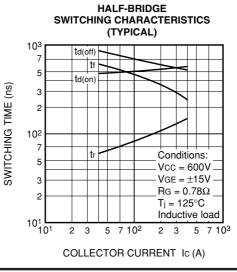


COLLECTOR CURRENT Ic (A)

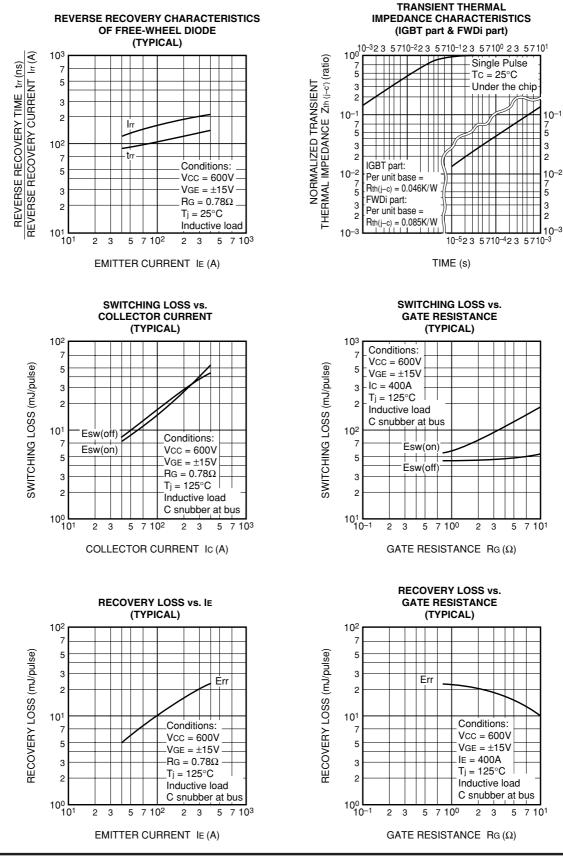
FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



EMITTER-COLLECTOR VOLTAGE VEC (V)

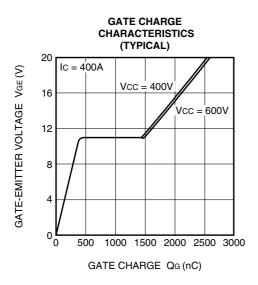


#### HIGH POWER SWITCHING USE





HIGH POWER SWITCHING USE





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